

MMBTH10-7-F

MMBTH10-7-F Information

www.heisener.co	 MMBTH10-7-F Diodes Incorporated Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF TRANS NPN VHF/UHF 25V SOT23-3 TO-236-3, SC-59, SOT-23-3 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MMBTH10-7-F Specifications

Manufacturer Part Number	MMBTH10-7-F	
Manufacturer	Diodes Incorporated	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - RF	
Package	TO-236-3, SC-59, SOT-23-3	
Series	-	
Transistor Type	NPN	
Voltage - Collector Emitter Breakdown (Max)	25V	
Frequency - Transition	650MHz	
Noise Figure (dB Typ @ f)	-	
Gain	-	
Power - Max	300mW	
DC Current Gain (hFE) (Min) @ Ic, Vce	60 @ 4mA, 10V	
Current - Collector (Ic) (Max)	50mA	
Operating Temperature	-55°C ~ 150°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	TO-236-3, SC-59, SOT-23-3	
Supplier Device Package	SOT-23-3	
	Report errors?	

MMBTH10-7-F Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MMBTH10-7-F Payment Methods



MMBTH10-7-F Shipping Methods



If you have any question about MMBTH10-7-F, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com